



# Peripheral/Power Drivers

LM75450, LM350

## LM75450, LM350 dual peripheral driver

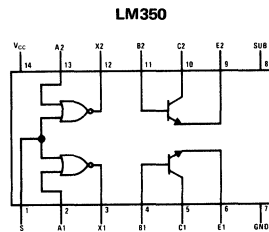
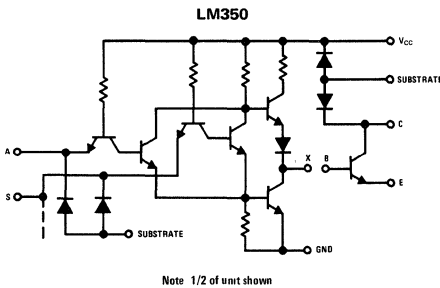
### general description

The LM75450 and LM350 are general purpose dual peripheral drivers. The design employs two standard TTL gates (NOR in LM350, NAND in LM75450) and two totally uncommitted, high-voltage, high-current NPN transistors. These transistors are capable of sinking 300 mA and will withstand 30V in the OFF state. Inputs are fully DTL/TTL compatible. The LM75450 meets or exceeds the specifications for both the SN75450 and the SN75450A and is a pin-for-pin replacement.

### features

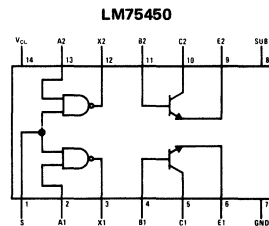
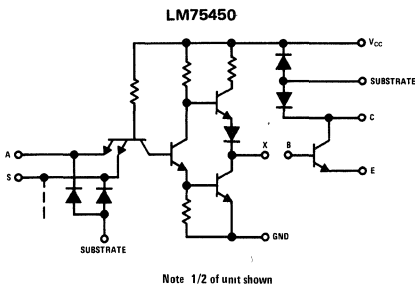
- High speed
- High sink current 300 mA
- Separate gates and transistors
- Both transistors can sink 300 mA simultaneously
- Transistors withstand 30V collector to emitter in the OFF state
- Input clamp diodes

## schematic and connection diagrams



Positive Logic:  $\overline{A \cdot S} = X$

Order Number LM350N  
See Package 22



Positive Logic:  $\overline{A \cdot S} = X$

Order Number LM75450N  
See Package 22

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### absolute maximum ratings (Note 1)

Supply Voltage $V_{CC}$	7V	Emitter-Base Voltage	5V
Input Voltage	5.5V	Continuous Collector Current	300 mA
$V_{CC}$ -to-Substrate Voltage	35V	Continuous Total Power Dissipation (Note 3)	800 mW
Collector-to-Substrate Voltage	35V	Operating Free-Air Temperature Range	0°C to 70°C
Collector-Base Voltage	35V	Storage Temperature Range	-65°C to 150°C
Collector-Emitter Voltage (Note 2)	30V		

### electrical characteristics

The following apply for 0°C ≤  $T_A$  ≤ 70°C,  $V_{CC}$  = 5V ±5%, for LM75450 and LM350 unless otherwise specified.  
**TTL GATES**

PARAMETER	COMMENTS	LOGIC INPUT	LOGIC OUTPUT	SUPPLY VOLTAGE	MIN	TYP	MAX	UNIT
Logical "1" Input Voltage	Logic Output ≤ 0.4V	$V_{IN}$	16 mA	4.75V	2			V
Logical "0" Input Voltage	Logic Output ≥ 2.4V	$V_{IN}$	-400 μA	4.75V			0.8	V
Logical "1" Output Voltage		0.8V	-400 μA	4.75V	2.4			V
Logical "0" Output Voltage		2V	16 mA	4.75V			0.4	V
Logical "1" Input Current	A Input	2.4V		5.25V			40	μA
	S Input	2.4V		5.25V			80	μA
	A Input	5.5V		5.25V			1	mA
	S Input	5.5V		5.25V			2	mA
Logical "0" Input Current	A Input	0.4V		5.25V			-1.6	mA
	S Input	0.4V		5.25V			-3.2	mA
Output Short Circuit Current	Note 4	0V	0V	5.25V	-18		-55	mA
Supply Current	Output Low	Per Package	LM350	5V	5.25V	8	14	mA
			LM75450	5V	5.25V	6	11	mA
	Output High	Per Package	LM350	0V	5.25V	4	7	mA
			LM75450	0V	5.25V	2	4	mA
Input Diode Clamp Voltage	$T_A = 25^\circ\text{C}, V_{SUB} = 0V$	-12 mA		5V			-1.5	V

### TRANSISTORS

PARAMETER	COMMENTS	BASE	EMITTER	COLLECTOR	MIN	TYP	MAX	UNIT
$BV_{CBO}$	$R_{BE} \leq 500\Omega$	0V		100 μA	35			V
$BV_{CER}$			0V	100 μA	30			V
$BV_{EBO}$		0V	100 μA		5			V
$V_{BE}$		10 mA	0V	100 mA	0.85	1		V
		30 mA	0V	300 mA	1.05	1.2		V
$V_{CE(sat)}$		10 mA	0V	100 mA	0.25	0.4		V
		30 mA	0V	300 mA	0.5	0.7		V
$h_{FE}$	$V_{CE} = 3V, T_A = 0^\circ\text{C}, \text{Note 5}$	$I_B$	0V	100 mA	20			
		$I_B$	0V	300 mA	25			
		$I_B$	0V	100 mA	25			
		$I_B$	0V	300 mA	30			
	$V_{CE} = 3V, T_A = 0^\circ\text{C}, \text{Note 5}$	$I_B$	0V	100 mA	25			
		$I_B$	0V	300 mA	25			
		$I_B$	0V	100 mA	25			
		$I_B$	0V	300 mA	30			

The following apply for  $V_{CC} = 5V, T_A = 25^\circ\text{C}$

#### TTL GATES (Note 6)

PARAMETER	TYP	MAX
$t_{pd1}$	10 ns	22 ns
$t_{pd0}$	5 ns	15 ns

#### TRANSISTORS

PARAMETER	TYP	MAX
$t_d$	6 ns	15 ns
$t_r$	12 ns	20 ns
$t_s$	6 ns	15 ns
$t_f$	8 ns	15 ns

#### GATES AND TRANSISTORS (Note 7)

PARAMETER	TYP
$t_{pd1}$	30 ns
$t_{pd0}$	30 ns
$t_r$	12 ns
$t_f$	15 ns

**Note 1:** All voltage values are with respect to ground terminal. Positive current is defined to be current into referenced pin.

**Note 2:** With base-emitter resistance ≤ 500Ω.

**Note 3:** The maximum junction temperature is 150°C. For operating at elevated temperatures the package must be derated based on a thermal resistance of 150°C/W  $\theta_{JA}$ .

**Note 4:** Only one output should be shorted at a time.

**Note 5:** These parameters are to be measured with less than 2% duty cycle.

**Note 6:** Delays measured with fanout of 10, 15 pF total load capacitance; measured from 1.5V input to 1.5V output.

**Note 7:** Delays measured with 50Ω load to 10V, 15 pF total load capacitance; measured from 1.5V input to 50% of output.